Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		ingaas and algaas and gaas and channel and light and strain and substrate and transistor and and electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:42
		ingaas and algaas and gaas and channel and light and strain and substrate and transistor and and electron near mobility(@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:42
		ingaas with electron near mobility with cm.sup.2/v*s and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:22
		S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) same strain and (algaas gaalas aluminum near gallium (arsenic arsenide)) same electron and (hemt high near electron near mobility near transistor transistor) and	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:41
		(ingaas indium near gallium near (arsenic arsenide) and "77" near k same nm and S95 and (algaas aluminum near gasllium near (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:30
And the control of th		S7 and hemt same strain and ingaas and algaas and	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 11:18
L1	175	ingaas and algaas and gaas and channel and light and strain and substrate and transistor and electron near mobility and (@ad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/11 16:35

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L2	3243	257/194,192,e31.053,e33.027,e21. 403,e21.407.ccls. 438/172.ccls. and L1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/11 16:36
L3	3393	257/194,192,e31.053,e33.027,e21. 403,e21.407.ccls. 438/172.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/11 16:36
L4	31	i3 and i1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/11 16:36
S1	1233	257/192.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:42
S2	1122	257/194.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:42
S3	193	257/195.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:42
54	538	257/190.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:42
S5	363	257/20.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:43

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S6	2724	S1 or S2 or S3 or S4 or S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:44
S7	2351	S6 and @ad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:46
S8	209	S7 and hemt and ingaas and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:47
S9	13	S7 and hemt same strain and ingaas and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:55
S10	6	S7 and hemt same strain and ingaas and algaas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:55
S11	6	S7 and hemt same strain and ingaas and algaas and wavelength and nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:56
S12	. 5	S7 and hemt same strain and ingaas and algaas and wavelength and nm and emission	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 15:05
S13	1	(("6163599") or ("0684959") or ("2001210819") or ("0621106") or ("2708863")).PN.	JPO	OR	OFF	2006/02/13 15:06
S14	0	("6163599").PN.	JPO	OR	OFF	2006/02/13 15:06
S15	0	("6-163599").PN.	ЈРО	OR	OFF	2006/02/13 15:06

C16	2	("C1C2F00") PN	LIC DCDLID.	OD	OFF	2006/02/12 15:07
S16		("6163599").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	OFF	2006/02/13 15:07
			IBM_TDB			
S17	0	(nec near corp).as. and "19940610".rlpd.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 15:38
S18	403329	(nec near corp).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 15:38
S19	245778	(nec near corp).as.	JPO	OR	ON	2006/02/13 15:38
S20	245778	(nec near corp).as. and jp "6163599"	JPO	OR	ON	2006/02/13 15:39
S21	0	(nec near corp).as. and jp and "6163599"	JPO	OR	ON	2006/02/13 15:39
S22	245778	(nec near corp).as. "6163599"	JPO	OR	ON	2006/02/13 15:39
S23	0	(nec near corp).as. and "6163599"	JPO	OR	ON	2006/02/13 15:39
S24	0	(nec near corp).as. and "6-163599"	JPO	OR	ON	2006/02/13 15:39
S25	0	"6-163599"	JPO	OR	ON	2006/02/13 15:40
S26	299	(nec near corp).as. and "19940610"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 15:40
S27	0	(nec near corp).as. and "19940610" and "163599"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/02/13 15:41
S28	299	(nec near corp).as. and "19940610"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 16:07

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S29		(nec near corp).as. and (negishi near hitoshi).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 16:08
S30	0	(nec near corp).as. and (negishi near hitoshi).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:08
S31	5	(negishi near hitoshi).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:08
S32	3	("5400739" "5490880" "5625204").PN. OR ("6099640"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:18
S33	8	fujitsu.as. and (saito near junji).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:22
S34	2	hitachi.as. and ((sasaki near yukio). in. or (tsuchiya near tadaitsu))	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:26
S35	0	hitachi.as. and (tsuchiya near tadaitsu).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:27
S36	0	hitachi.as. and (tadaitsu).in.	US-PGPUB; USPAT; USOCR	OR-	ON	2006/02/13 16:27
S37	0	(tadaitsu).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:28
S38	33	(sawada near minoru).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/13 16:28
S39	18	(sawada near minoru).in. and sanyo.as.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 14:44
S40	2	("6639254").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/14 15:09
S41	9	algaas same ingaas near strain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 15:13

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S42	632	(ishikawa near makoto).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 15:13
S43	114	(ishikawa near makoto).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:13
S44	2	(ishikawa near makoto).in. and hemt	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:14
S45	0	(ishikawa near makoto).in. and nec. as.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:14
S46	114	(ishikawa near makoto).in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:15
S47	0	JP02254412	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:15
S48	7	"2254412"	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:39
S49	0	(feng near zhao).in. and algaas and ingaas	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:40
S50 ·	5	(zhao).in. and algaas and ingaas	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:41
S51	0	(strau).in. and algaas and ingaas	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:41
S52	0	(straub).in. and algaas and ingaas	US-PGPUB; USPAT; USOCR	OR ·	ON	2006/02/14 15:41
S53	0	(bernklau).in. and algaas and ingaas	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 15:41
S54	12	(US-5825796-\$ or US-5945690-\$ or US-6639254-\$ or US-5569954-\$ or US-5625204-\$ or US-5773853-\$ or US-5751029-\$ or US-5650642-\$ or US-5404032-\$ or US-5258632-\$ or US-5406099-\$). did.	USPAT	OR	ON	2006/02/14 16:29

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S55	10	S54 and mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 16:30
S56	10	S54 and electron near mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/02/14 16:31
S57	4	algaas same ingaas near strain and electron near mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 16:31
S58	4	algaas same ingaas near strain and electron near mobility and @ad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 16:32
S59	28	("4742379" "4792832" "5021857" "5041393" "5060030" "5091759" "5140386" "5196359" "5270228" "5272109" "5285087" "5324682" "5330932" "5364816" "5372675" "5504353" "5514605" "5521404" "5550388" "5641977" "5760427" "5770525" "5811844" "5900653" "6060402").PN. OR ("6307221"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 17:49
S60	. 24	S59 and mobility	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 17:49
S61	23	S59 and mobility and @ad<"20021225"	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/14 17:50
S62	3721	ingaas same algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:15

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S63	23717685	@ad<"20021225" @rlad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 18:57
S64	896179	fet hemt field near effect near transistor or high near electron near mobility near (field near effect near transistor fet) transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 18:59
S65	514599	strain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 18:59
S66	571	strain near channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 18:59
S67	7	S62 and S63 and S64 and S66	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:00
S68	4483	(ingaas gainas) same (algaas gaalas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:19
S69	7	S68 and S63 and S64 and S66	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:17
S70	5626	(ingaas gainas gallium near indian near (arsenide arsenic)) same (algaas gaalas aluminum near galium (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:21

C71	8	C70 and C62 and C64 and C66	LIC DCDLID	OB	ON	2006/00/12 10:22
S71	8	S70 and S63 and S64 and S66	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:22
S72	9019	(ingaas gainas gallium near indium near (arsenide arsenic)) same (algaas gaalas aluminum near gallium (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:39
S73	8	S72 and S63 and S64 and S66	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/12 19:22
S74	6366	hemt or (high near electron near mobility near transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:41
S75	872	channel near5 (InGaAs or GaAsIn)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:42
S76	2820	(n-type near2 AlGaAs) or n-AlGaAs or ((electron near supply\$3) near5 AlGaAs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:42
S77	164	InGaAs same (peak near5 wavelength)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S78	3	S74 and S75 and S76 and S77	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43

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S79	5	S75 and S76 and S77	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S80	872	S75 andl3 and (peak near5 wavelength)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S81	225	S75 and S76	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S82	15	S81 and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S83	884	S76 and (InGaAs or GaAsIn)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:43
S84	30	S83 and (peak near wavelength)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:44
S85	435212	"257"/\$.ccls. "438"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:44
S86	5740	257/187,192,194,E31.053,E33.027, E33.032,E33.053,E21.403,E21.407. ccls. 438/22,46.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:45

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S87	27011996	@ad<"20050623" @rlad<"20050623"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/09/19 17:45
S88	23721359	@ad<"20021225" @rlad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:46
S89	2	S78 and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:58
S90	13999	ingaas (indium near gallium near arsenic) same "77" near k with nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 17:59
S91	13999	ingaas (indium near gallium near arsenic) same "77" near k with nm and S85 and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	·OR	ON	2006/09/19 18:04
S92	0	(ingaas indium near gallium near arsenic) same "77" near k with nm and S85 and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:05
S93	0	(ingaas indium near gallium near arsenic) same "77" near k same nm and S85 and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:05
S94	1	(ingaas indium near gallium near arsenic) same "77" near k same nm and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:12

S95	23721359	@ad<"20021225"	US-PGPUB;	OR	ON	2006/09/19 18:12
393	23/21339	@rlad<"20021225"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		ON	2000/09/19 16:12
S96	. 20	(ingaas indium near gallium near arsenic) and "77" near k same nm and S95	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:12
S97	18	(ingaas indium near gallium near arsenic) and "77" near k same nm and S95 and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:12
S98	18	(ingaas indium near gallium near arsenic) and "77" near k same nm and S95 and (algaas aluminum near gasllium near arsenic)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:29
S99	18	(ingaas indium near gallium near (arsenic arsenide)) and "77" near k same nm and S95 and (algaas aluminum near gasllium near (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:30
S10 0	17	(ingaas indium near gallium near (arsenic arsenide)) and "77" near k same wavelength and S95 and (algaas aluminum near gasllium near (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 19:14
S10 1	17	S100 not "I8"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:31
S10 2	4	S100 not S99	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 18:32

S10 3	22	(ingaas indium near gallium near (arsenic arsenide)) and "77" near k same (wavelength ".mu.m" nm) and S95 and (algaas aluminum near gasllium near (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 19:17
S10 4	0	".mu.m"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/19 19:17
S10 5	0	".mu.m"\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:25
S10 6	. 2	"6573527".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:26
S10 7	0	"6573527".pn. and hemt and strain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON .	2006/09/20 10:26
S10 8	0	"6573527".pn. and hemt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/09/20 10:26
S10 9	1	"6573527".pn. and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:27
S11 0	11104	(ingaas gainas gallium near indium near (arsenide arsenic)) and (algaas gaalas aluminum near gallium (arsenic arsenide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:39

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S11 1	23721359	@ad<"20021225" @rlad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:41
S11 2	266	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) same strain and (algaas gaalas aluminum near gallium (arsenic arsenide)) same electron and (hemt high near electron near mobility near transistor transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 11:46
S11 3	29	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) same strain and (algaas gaalas aluminum near gallium (arsenic arsenide)) same electron and (hemt high near electron near mobility near transistor transistor) and graph	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:41
S11 4	112	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) same strain and (algaas gaalas aluminum near gallium (arsenic arsenide)) same electron and (hemt high near electron near mobility near transistor transistor) and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:41
S11 5	6	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) same strain and (algaas gaalas aluminum near gallium (arsenic arsenide)) same electron and (hemt high near electron near mobility near transistor transistor) and "77" near k	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 10:43
S11 6	14	("4830980" "4908325" "5118637").PN. OR ("5196359"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 10:48
S11 7	9	("3821783" "4688068" "4872046" "5016252" "5212404" "5263040").PN. OR ("5569954"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 11:00
S11 .8	9	("4894836" "4974231" "5146466").PN. OR ("5263040"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 11:09

S11 9	76	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) and (algaas gaalas aluminum near gallium (arsenic arsenide)) and "77" near k	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 11:59
S12 0	40	S111 and (ingaas gainas gallium near indium near (arsenide arsenic)) and (algaas gaalas aluminum near gallium (arsenic arsenide)) and "77" near k same (wavelength peak pl nm emision)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 11:48
S12 1	12	hemt and ingaas same channel and emission near peak	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:22
S12 2	11	hemt and ingaas same channel and emission near peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:01
S12 3	11	hemt and ingaas same channel and emission near3 peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:01
S12 4	. 11	hemt and ingaas same channel and emission near5 peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:03
S12 5	11	hemt and ingaas same channel and emission near5 peak near5 wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:03
S12 6	10	hemt and ingaas same channel and emission near5 peak near5 wavelength and S111	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:26

S12 7	2	("5,060,030").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/20 12:22
S12 8	105	ingaas and emission near5 peak near5 wavelength and S111	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:26
S12 9	127	(ingaas indium near gallium near arsenide) and emission near5 peak near5 wavelength and S111	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:29
S13 0	279	(ingaas indium near gallium near arsenide) and emission near5 peak and S111	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:29
S13 1	116	(ingaas indium near gallium near arsenide) and emission near5 peak and S111 and graph	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 12:37
S13 2	50	(ingaas indium near gallium near arsenide) and emission near5 peak and S111 and graph and channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:38
S13 3	2	("6639254").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/20 16:38
S13 4		S133 and hemt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:42

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S13 5	849291	transistor ingaas same channel and peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:43
S13 6	23	transistor and ingaas same channel and peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:50
S13 7	0	transistor and ingaas same (two-dimensional two near dimensional) near gas and peak near wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:52
S13 8	18	transistor and ingaas same (two-dimensional two near dimensional) near gas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:52
S13 9	20	ingaas same (two-dimensional two near dimensional) near gas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON _.	2006/09/20 16:57
S14 0	73	2-deg	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:56
S14 1	21	ingaas same (2-deg two-dimensional two near dimensional) near gas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 16:57
S14 2	21	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg two-dimensional two near dimensional) near gas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 17:01

S14 3	25	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 17:10
S14 4	22	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and wavelength and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 17:28
S14 5	2	("6849866").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/20 21:06
S14 6	2	("6849866").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/20 21:14
S14 7	22	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and wavelength and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:02
S14 8	1	S147 and "20030006407".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 21:15
S14 9		("5010374").PN. OR ("6849866"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 21:18

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S15 0	30	(US-20040069991-\$).did. or (US-5625204-\$ or US-5751029-\$ or US-5900653-\$ or US-5258632-\$ or US-5650642-\$ or US-6307221-\$ or US-5773853-\$ or US-5404032-\$ or US-5406099-\$ or US-5945690-\$ or US-6593603-\$ or US-6639254-\$ or US-5825796-\$ or US-5569954-\$ or US-5550388-\$ or US-5751027-\$ or US-6177684-\$ or US-5796359-\$ or US-6242293-\$ or US-4688068-\$ or US-5486705-\$ or US-5832018-\$ or US-6229153-\$ or US-5762706-\$ or US-5441913-\$ or US-4780877-\$). did. or (US-5015099-\$ or	US-PGPUB; USPAT	OR	ON	2006/09/20 21:51
		US-5126803-\$ or US-5585957-\$).				
S15 1	20	did. S150 and electron near mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 21:52
S15 2	20	S150 and electron near mobility and ingaas and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 21:52
S15 3	. 3	("4830980" "4908325" "5118637").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 22:00
S15 4	8	"cm.sup.2 /Vs"	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 22:01
S15 5	244970	"cm.sup.2"	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 22:01
S15 6	260	(ingaas gainas indium near2 gallium near2 arsenide) same "cm.sup.2"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:01
S15 7	6	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and transistor and "cm.sup.2"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/09/20 22:02

S15 8	23721359	@ad<"20021225" @rlad<"20021225"	US-PGPUB; USPAT; USOCR; EPO; JPÓ; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:02
S15 9	5	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and transistor and "cm.sup.2" and S158	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:05
S16 0	2	(ingaas gainas indium near2 gallium near2 arsenide) same (2-deg 2deg two-dimensional two near dimensional) near gas and transistor and "cm.sup.2" and S158 and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:09
S16 1	6	("4705361" "4734750" "4745447").PN. OR ("4958203"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 22:08
S16 2	17262	aluminum near2 gallium near2 arsenide algaas gaalas	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/20 22:09
S16 3	537	(ingaas gainas indium near2 gallium near2 arsenide) and S162 and transistor and "cm.sup.2" and S158 and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:10
S16 4	636	(ingaas gainas indium near2 gallium near2 arsenide) and S162 and transistor and "cm.sup.2" and S158	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:45
S16 5	7	(ingaas gainas indium near2 gallium near2 arsenide) and S162 and transistor and "300" near "k" same mobility and S158	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:37
S16 6	2	"5060030".pn. and mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 22:44

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S16 7	2	"6639254".pn. and mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/09/20 22:44
S16 8	125	(ingaas gainas indium near2 gallium near2 arsenide) and S162 and transistor and "cm.sup.2" same mobility and S158	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 23:18
S16 9	0	"5258632".pn. and "300" near k	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 23:18
S17 0	0	"5258632".pn. and ("300" near k 300k)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/20 23:18
S17 1	2	"5449928".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 02:56
S17 2	2	"20030006407".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 02:57
S17 3	298	ingaas with channel same transistor and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 02:58
S17 4	8	ingaas with channel same transistor and (@ad<"20021225" @rlad<"20021225") and algaas with electron near supplying	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:01

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S17 5	21	(ingaas "In.sub.y" "Ga.sub.1-y" As indium near gallium near arsenide) with channel same transistor and (@ad<"20021225") and algaas with electron near supplying	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:03
S17 6	9	(ingaas indium near gallium near arsenide) with channel same transistor and (@ad<"20021225" @rlad<"20021225") and algaas with electron near supplying	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:06
S17 7	1	ingaas same emission near wavelength with nm same electron near mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:07
S17 8	0	ingaas same emission near wavelength with nm same electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:08
S17 9	57	ingaas same emission near wavelength with nm and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:11
S18 0	354	ingaas same electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:08
S18 1	0	S179 and S180	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:08
S18 2	0	ingaas same emission near wavelength with nm and (@ad<"20021225" @rlad<"20021225") and ingaas same electron near mobility	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:09

S18 3	1	"20030006407".pn. and channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:14
S18 4	1	"5258632".pn. and ingaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:20
S18 5	1356	ingaas and electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:20
S18 6	354	ingaas same electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:20
S18 7	220	ingaas with electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:21
S18 8	23844469	ingaas with electron near mobility and ingaas with emission(@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/07/09 03:21
S18 9	3	ingaas with electron near mobility and ingaas with emission and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:22
S19 0	5	ingaas with electron near mobility with nm and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:22

						
S19 1	220	ingaas with electron near mobility and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:23
S19 2	1	ingaas with electron near mobility and (@ad<"20021225" @rlad<"20021225") and "5258632". pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:23
S19 3	2	ingaas with electron near mobility with "cm.sup.2 /Vs "and (@ad<"20021225" @rlad<"20021225") and "5258632". pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:23
S19 4	2	ingaas with electron near mobility with "cm.sup.2 /Vs"and (@ad<"20021225" @rlad<"20021225") and "5258632". pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:24
S19 5	0	ingaas with electron near mobility with "cm.sup.2 /Vs" and (@ad<"20021225" @rlad<"20021225") and "5258632". pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:44
S19 6.	23844468	ingaas with electron near mobility with "cm.sup.2 /Vs"and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:24
S19 7	0	ingaas with electron near mobility with "cm.sup.2 /Vs" and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2007/07/09 03:24
S19 8	3	ingaas with electron near mobility with "cm.sup.2" and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:37

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S19 9	193	ingaas with emission with wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:37
S20 0	145	ingaas with emission with wavelength and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:38
S20 1	56	ingaas with emission with wavelength with (nanometer nm) and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:38
S20 2	145	ingaas with emission with wavelength and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/07/09 03:40
\$20 3	97	ingaas with emission with wavelength and (@ad<"20021225" @rlad<"20021225") and algaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2007/07/09 03:41
S20 4	1	ingaas with emission with wavelength and (@ad<"20021225" @rlad<"20021225") and algaas and ingaas with channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:41
S20 5	6	("20030006407" "5449928" "66392 54").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 03:44
S20 6	3	("20030006407" "5449928" "66392 54").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2007/07/09 03:45

S20 7	1	("20010011733").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2007/07/09 03:45
S20 8	11	ingaas with channel and algaas and ingaas with (light emission wavelength) with (nanometer nm) and (@ad<"20021225") @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 11:34
S20 9	2	"20010011733".pn. and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 11:30
S21 0	40	transistor and ingaas and algaas and ingaas with (light emission wavelength) with (nanometer nm) and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 11:34
S21 1	232	transistor and ingaas and algaas and ingaas with (light emission wavelength) and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 11:34
S21 2	21	transistor and ingaas and algaas and ingaas with (light emission wavelength) and (@ad<"20021225" @rlad<"20021225") and ingaas with channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:07
S21 3	66	transistor and ingaas and algaas and (light near emission) and (@ad<"20021225" @rlad<"20021225") and channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:18
S21 4	9	(phemt pseudomorphic near hemt p adj hemt) and light near emission and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:41

S21 5	1001	ingaas and algaas and gaas and channel and light and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:42
S21 6	262	ingaas and algaas and gaas and channel and light and strain and substrate and transistor and (@ad<"20021225" @rlad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:42
S21 7	175	ingaas and algaas and gaas and channel and light and strain and substrate and transistor and electron near mobility and (@ad<"20021225")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:49
S21 8	0	"5486705".pn. and light	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:49
S21 9	0	"5486705".pn. and emission	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:49
S22 0	0	"5486705".pn. and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50
S22 1	0	"5486705".pn. and "5060030"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50
S22 2	0	"5060030".pn. and light	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50

S22 3	2	"5060030".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50
S22 4	0	"5060030".pn. and emission	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50
S22 5	0	"5060030".pn. and wavelength	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:50
S22 6	. 0	"5258632".pn. and light	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/09 12:51
S22 7	0	"5258632".pn. and emission	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/11 16:31